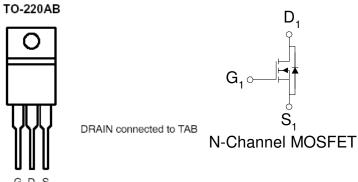
## N-Channel 100-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

•	Low $r_{DS(on)}$ provides higher efficiency and
	extends battery life

- Low thermal impedance copper leadframe TO-220 saves board space
- Fast switching speed
- High performance trench technology

PRODUCT SUMMARY			
V <sub>DS</sub> (V)	$r_{DS(on)} m(\Omega)$	$I_{D}(A)$	
100	44 @ V <sub>GS</sub> = 10V	zo <sup>a</sup>	
100	$64 @ V_{GS} = 4.5V$	70 <sup>a</sup>	



ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)				
Parameter		Symbol	Limit	Units
Drain-Source Voltage			100	V
Gate-Source Voltage			±20	
Continuous Drain Current <sup>a</sup>	$T_C=25^{\circ}C$	$I_{\mathrm{D}}$	110	A
Pulsed Drain Current <sup>b</sup>		$I_{DM}$	390	A
Continuous Source Current (Diode Conduction) <sup>a</sup>			110	A
Power Dissipation <sup>a</sup>	T <sub>C</sub> =25°C	$P_{\mathrm{D}}$	300	W
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 175	°C

Top View

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Maximm	Units	
Maximum Junction-to-Ambient <sup>a</sup>	R <sub>0</sub> JA	62.5	°C/W	
Maximum Junction-to-Case	$R_{ heta JC}$	0.5	°C/W	

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## Notes

- a. Package Limited
- b. Pulse width limited by maximum junction temperature

Analog Power AM70N10-44P

SPECIFICATIONS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)							
D	Symbol	Test Conditions	Limits			TT •4	
Parameter			Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	VGS(th)	$V_{DS} = V_{GS}$ , $I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = 20 \text{ V}$			±100	nA	
Zara Cata Valtaga Drain Current	IDSS	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zero Gate Voltage Drain Current	IDSS	$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25		
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	120			A	
D i G O D i A	4	$V_{GS} = 10 \text{ V}, I_{D} = 2 \text{ A}$			44	mΩ	
Drain-Source On-Resistance <sup>A</sup>	r <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 2 \text{ A}$			64		
Forward Tranconductance <sup>A</sup>	$g_{ m fs}$	$V_{DS} = 15 \text{ V}, I_D = 2 \text{ A}$		30		S	
Diode Forward Voltage	Vsd	Is = 2 A, VGS = 0 V		1.1		V	
Dynamic <sup>b</sup>							
Total Gate Charge	Qg	Vac 15 V Vac 45 V		70		nC	
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V},$ $I_{D} = 90 \text{ A}$		10			
Gate-Drain Charge	$Q_{\mathrm{gd}}$	1D = 90  A		20			
Turn-On Delay Time	t <sub>d(on)</sub>			10			
Rise Time	t <sub>r</sub>	$V_{DD} = 25 \text{ V}, R_L = 25 \Omega, I_D = 34 \text{ A},$		30		nS	
Turn-Off Delay Time	td(off)	$V_{GEN} = 10 V$		30			
Fall-Time	tf			30			

## Notes

- a. Pulse test:  $PW \le 300$ us duty cycle  $\le 2\%$ .
- b. Guaranteed by design, not subject to production testing.

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## Package Information

